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CERTIFICATE OF TRANSMISSION BY FACSIMILE (37 CFR 1.8)		Docket No. 990326	
Applicant(s): LIPPERT et al.			
Serial No. 09/319,699	Filing Date FEB 04 2002 July 1999	Examiner Wille, Douglas A	Group Art Unit 2814

Invention: Silicon Germanium Hetero Bipolar Transistor

CONFIRMATION

I hereby certify that this Initial Response to Notice of Abandonment
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Karl Hormann
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IN THE UNITED STATES PATENT & TRADEMARK OFFICE

Application No.: 09/319,699

Filed: 19 July 1999

Inventor: Lippert et al.

For: Silicon Germanium Hetero Bipolar Transistor

Examiner: Wille, Douglas A.

Art Unit: 2814

86 Sparks Street

Cambridge, MA 02138-2216

5 December 2001

Hon.

Assistant Commissioner for Patents

Box PCT

Washington, DC 20231

CONFIRMATION

Initial Response to Notice of Abandonment

Sir:

This is in partial response to the Notice of Abandonment dated 23 November 2001 alleging failure of a timeous response to an Official Action dated 28 March 2001.

No such action appears to have been received by the undersigned attorney; but the overseas client has been contacted to determine whether the subject matter of the application warrants filing a petition for revival of the application. (The last communication from this office to the PTO was an Amendment dated 12 December 2000.)

Respectfully submitted,

Karl Hormann

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